NSN 5961-01-107-9021

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Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-107-9021 **Inclosure Material:** Plastic **Overall Length:** 3.620 inches **Overall Height:** 1.417 inches **Overall Width:** 0.787 inches **Mounting Facility Quantity: Component Name And Quantity:** 2 semiconductor device thyristor **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon all semiconductor device thyristor Voltage Rating In Volts Per Characteristic: 1200.0 repetitive peak reverse voltage all semiconductor device thyristor and 1300.0 nonrepetitive peak reverse voltage all semiconductor device thyristor and 1200.0 repetitive peak off-state voltage all semiconductor device thyristor **Current Rating Per Characteristic:** 40.00 amperes forward current, total rms universal all semiconductor device thyristor and 70.00 amperes forward current, total rms horsepower metric all semiconductor device thyristor **Power Rating Per Characteristic:** 20.0 watts small-signal input power, common-collector blank all semiconductor device thyristor and 2.0 watts small-signal input power, common-collector universal all semiconductor device thyristor **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius case **Test Data Document:** 10110-140183 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 3 screw and 2 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:**